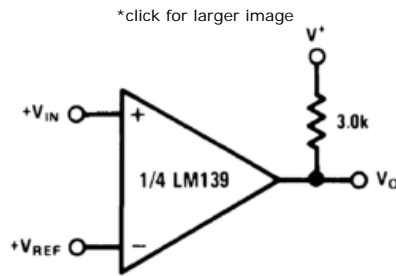


LM339 - Low Power Low Offset Voltage Quad Comparator

Features

Wide supply voltage range	
LM139/139A Series	2 to 36 V _{DC} or ±1 to ±18 V _{DC}
LM2901:	2 to 36 V _{DC} or ±1 to ±18 V _{DC}
LM3302:	2 to 28 V _{DC} or ±1 to ±14 V _{DC}
Very low supply current drain (0.8 mA) - independent of supply voltage	
Low input biasing current:	25 nA
Low input offset current:	±5 nA
Offset voltage:	±3 mV
Input common-mode voltage range includes GND	
Differential input voltage range equal to the power supply voltage	
Low output saturation voltage:	250 mV at 4 mA
Output voltage compatible with TTL, DTL, ECL, MOS and CMOS logic systems	

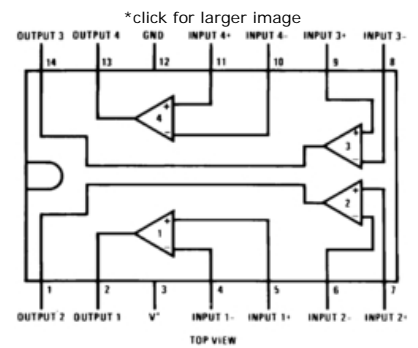
Typical Application



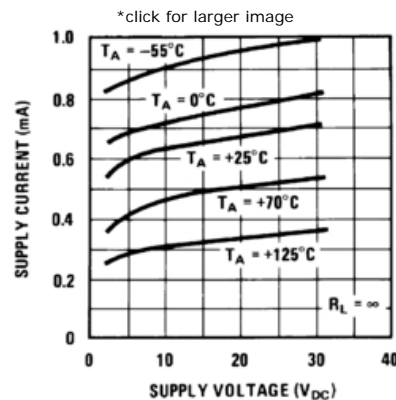
Parametric Table

Response Time	0.5 us
Output Bus	Open Drain
Supply Min	2 Volt
Supply Max	36 Volt
Channels	4 Channels
Offset Voltage max, 25C	2, 5 mV
Output Current	16 mA
Input Range	V _{cm} to V-
Supply Current Per Channel	0.2 mA
PowerWise Rating 3	100 uA x us
Max Input Bias Current	400 nA
Special Features	Undefined
Temperature Min	-25 deg C
Temperature Max	85 deg C
Function	Comparator

Connection Diagram



Typical Performance



Applications

- High precision comparators
- Reduced V_{OS} drift over temperature
- Eliminates need for dual supplies
- Allows sensing near GND
- Compatible with all forms of logic
- Power drain suitable for battery operation



RoHS Compliance Information

LM139/LM239/LM339/LM2901/LM3302 Low Power Low Offset Voltage Quad Comparators

Package Availability, Models

Part Number	Package							Factory Lead Time		Models			Std Pack Size	Package Marking Format
	Type	Pins	Spec.	MSL Rating	Peak Reflow	RoHS Report	CAD Symbols	Weeks	Qty					
LM339AM	SOIC NARROW	14	STD	1	235	RoHS	Download	Full production		N/A			rail of 55	NSUZXYTT LM339AM
			NOPB	1	260			6 weeks	2500					
LM339M	SOIC NARROW	14	STD	1	235	RoHS	Download	Full production		N/A			rail of 55	NSUZXYTT LM339M
			NOPB	1	260			6 weeks	2000					
LM339AMX	SOIC NARROW	14	STD	1	235	RoHS	Download	Full production		N/A			reel of 2500	NSUZXYTT LM339AM
			NOPB	1	260			6 weeks	7500					
LM339MX	SOIC NARROW	14	STD	1	235	RoHS	Download	Full production		N/A			reel of 2500	NSUZXYTT LM339M
			NOPB	1	260			6 weeks	5000					
LM339AN	MDIP	14	STD	1	NA	RoHS	Download	Full production		N/A			rail of 25	NSUZXYTTE# LM339AN
			NOPB	1	NA			8 weeks	3000					
LM339N	MDIP	14	STD	1	NA	RoHS	Download	Full production		N/A			rail of 25	NSUZXYTTE# LM339N
			NOPB	1	NA			6 weeks	3000					
LM339J	CERDIP	14	STD	1	NA	RoHS	Download	Full production		N/A			rail of 25	NSUZXYTTE# LM339J
					6 weeks			500						
LM339 MDC	Unpackaged Die							Obsolete		N/A			tray of N/A	-
								N/A	40000					
LM339 MWC	Wafer							Lifetime buy		N/A			wafer jar of N/A	-
								N/A	75000					

Obsolete Versions

Obsolete Part	Alternate Part or Supplier	Source	Last Time Buy Date
LM339AJ	LM339AN	NATIONAL SEMICONDUCTOR	04/04/95

General Description

The LM139 series consists of four independent precision voltage comparators with an offset voltage specification as low as 2 mV max for all four comparators. These were designed specifically to operate from a single power supply over a wide range of voltages. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage. These comparators also have a unique characteristic in that the input common-mode voltage range includes ground, even though operated from a single power supply voltage.

Application areas include limit comparators, simple analog to digital converters; pulse, squarewave and time delay generators; wide range VCO; MOS clock timers; multivibrators and high voltage digital logic gates. The LM139 series was designed to directly interface with TTL and CMOS. When operated from both plus and minus power supplies, they will directly interface with MOS logic- where the low power drain of the LM339 is a distinct advantage over standard comparators.

Reliability Metrics

Part Number	Process	EFR Reject	EFR Sample Size	PPM *	LTA Rejects	LTA Device Hours	FITS	MTTF (Hours)
LM339 MDC	SLM	0	42786	0	0	3352500	2	951281028
LM339 MWC	SLM	0	42786	0	0	3352500	2	951281028
LM339AM	SLM	0	42786	0	0	3352500	2	951281028
LM339AMX	SLM	0	42786	0	0	3352500	2	951281028
LM339AN	SLM	0	42786	0	0	3352500	2	951281028
LM339J	SLM	0	42786	0	0	3352500	2	951281028
LM339M	SLM	0	42786	0	0	3352500	2	951281028
LM339MX	SLM	0	42786	0	0	3352500	2	951281028
LM339N	SLM	0	42786	0	0	3352500	2	951281028

Note: The Early Failure Rates were calculated as point estimates. The Long Term Failure Rates were calculated at 60% confidence using the Arrhenius equation at 0.7eV activation energy and derating the assumed stress temperature of 150°C to an application temperature of 55°C.

For more information on Reliability Metrics, please click here.

Absolute Maximum Ratings (Note 10)

Distributors for availability and specifications.

If Military/Aerospace specified devices are required,
please contact the National Semiconductor Sales Office/

	LM139/LM239/LM339			LM3302
	LM139A/LM239A/LM339A	LM2901		
Supply Voltage, V^+	36 V_{DC} or $\pm 18 V_{DC}$			28 V_{DC} or $\pm 14 V_{DC}$
Differential Input Voltage (Note 8)	36 V_{DC}			28 V_{DC}
Input Voltage	$-0.3 V_{DC}$ to $+36 V_{DC}$			$-0.3 V_{DC}$ to $+28 V_{DC}$
Input Current ($V_{IN} < -0.3 V_{DC}$), (Note 3)	50 mA			50 mA
Power Dissipation (Note 1)				
Molded DIP	1050 mW			1050 mW
Cavity DIP	1190 mW			
Small Outline Package	760 mW			
Output Short-Circuit to GND, (Note 2)	Continuous			Continuous
Storage Temperature Range	-65°C to $+150^\circ\text{C}$			-65°C to $+150^\circ\text{C}$
Lead Temperature (Soldering, 10 seconds)	260 $^\circ\text{C}$			260 $^\circ\text{C}$
Operating Temperature Range				-40°C to $+85^\circ\text{C}$
LM339/LM339A	0 $^\circ\text{C}$ to $+70^\circ\text{C}$			
LM239/LM239A	-25°C to $+85^\circ\text{C}$			
LM2901	-40°C to $+85^\circ\text{C}$			
LM139/LM139A	-55°C to $+125^\circ\text{C}$			
Soldering Information				
Dual-In-Line Package				
Soldering (10 seconds)	260 $^\circ\text{C}$			260 $^\circ\text{C}$
Small Outline Package				
Vapor Phase (60 seconds)	215 $^\circ\text{C}$			215 $^\circ\text{C}$
Infrared (15 seconds)	220 $^\circ\text{C}$			220 $^\circ\text{C}$
See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.				
ESD rating (1.5 k Ω in series with 100 pF)	600V			600V

Electrical Characteristics $(V^+ = 5 V_{DC}, T_A = 25^\circ\text{C}$, unless otherwise stated)

Parameter	Conditions	LM139A			LM239A, LM339A			LM139			Units
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage	(Note 9)	1.0	2.0		1.0	2.0		2.0	5.0		mV _{DC}
Input Bias Current	$I_{IN(+)}$ or $I_{IN(-)}$ with Output in Linear Range, (Note 5), $V_{CM} = 0V$	25	100		25	250		25	100		nA _{DC}
Input Offset Current	$I_{IN(+)} - I_{IN(-)}$, $V_{CM} = 0V$	3.0	25		5.0	50		3.0	25		nA _{DC}
Input Common-Mode Voltage Range	$V^+ = 30 V_{DC}$ (LM3302, $V^+ = 28 V_{DC}$) (Note 6)	0	$V^+ - 1.5$		0	$V^+ - 1.5$		0	$V^+ - 1.5$		V _{DC}
Supply Current	$R_L = \infty$ on all Comparators, $R_L = \infty$, $V^+ = 36V$, (LM3302, $V^+ = 28 V_{DC}$)	0.8	2.0		0.8	2.0		0.8	2.0		mA _{DC}
					1.0	2.5		1.0	2.5		mA _{DC}
Voltage Gain	$R_L \geq 15 k\Omega$, $V^+ = 15 V_{DC}$ $V_O = 1 V_{DC}$ to $11 V_{DC}$	50	200		50	200		50	200		V/mV
Large Signal Response Time	$V_{IN} = \text{TTL Logic Swing}$, $V_{REF} = 1.4 V_{DC}$, $V_{RL} = 5 V_{DC}$	300			300			300			ns

Electrical Characteristics (Continued) $(V^+ = 5 V_{DC}, T_A = 25^\circ\text{C}, \text{ unless otherwise stated})$

Parameter	Conditions	LM139A			LM239A, LM339A			LM139			Units
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
	$R_L = 5.1 \text{ k}\Omega$										
Response Time	$V_{RL} = 5 V_{DC}, R_L = 5.1 \text{ k}\Omega,$ (Note 7)	1.3			1.3			1.3			μs
Output Sink Current	$V_{IN(-)} = 1 V_{DC}, V_{IN(+)} = 0,$ $V_O \leq 1.5 V_{DC}$	6.0	16		6.0	16		6.0	16		mA_{DC}
Saturation Voltage	$V_{IN(-)} = 1 V_{DC}, V_{IN(+)} = 0,$ $I_{SINK} \leq 4 \text{ mA}$	250	400		250	400		250	400		mV_{DC}
Output Leakage Current	$V_{IN(+)} = 1 V_{DC}, V_{IN(-)} = 0,$ $V_O = 5 V_{DC}$	0.1			0.1			0.1			nA_{DC}

Electrical Characteristics $(V^+ = 5 V_{DC}, T_A = 25^\circ\text{C}, \text{ unless otherwise stated})$

Parameter	Conditions	LM239, LM339			LM2901			LM3302			Units
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage	(Note 9)	2.0	5.0		2.0	7.0		3	20		mV_{DC}
Input Bias Current	$I_{IN(+)}$ or $I_{IN(-)}$ with Output in Linear Range, (Note 5), $V_{CM} = 0V$	25	250		25	250		25	500		nA_{DC}
Input Offset Current	$I_{IN(+)} - I_{IN(-)}, V_{CM} = 0V$	5.0	50		5	50		3	100		nA_{DC}
Input Common-Mode Voltage Range	$V^+ = 30 V_{DC}$ (LM3302, $V^+ = 28 V_{DC}$) (Note 6)	0	$V^+ - 1.5$		0	$V^+ - 1.5$		0	$V^+ - 1.5$		V_{DC}
Supply Current	$R_L = \infty$ on all Comparators, $R_L = \infty, V^+ = 36V,$ (LM3302, $V^+ = 28 V_{DC}$)	0.8	2.0		0.8	2.0		0.8	2.0		mA_{DC}
		1.0	2.5		1.0	2.5		1.0	2.5		mA_{DC}
Voltage Gain	$R_L \geq 15 \text{ k}\Omega, V^+ = 15 V_{DC}$ $V_O = 1 V_{DC}$ to $11 V_{DC}$	50	200		25	100		2	30		V/mV
Large Signal Response Time	$V_{IN} = \text{TTL Logic Swing}, V_{REF} =$ $1.4 V_{DC}, V_{RL} = 5 V_{DC},$ $R_L = 5.1 \text{ k}\Omega,$	300			300			300			ns
Response Time	$V_{RL} = 5 V_{DC}, R_L = 5.1 \text{ k}\Omega,$ (Note 7)	1.3			1.3			1.3			μs
Output Sink Current	$V_{IN(-)} = 1 V_{DC}, V_{IN(+)} = 0,$ $V_O \leq 1.5 V_{DC}$	6.0	16		6.0	16		6.0	16		mA_{DC}
Saturation Voltage	$V_{IN(-)} = 1 V_{DC}, V_{IN(+)} = 0,$ $I_{SINK} \leq 4 \text{ mA}$	250	400		250	400		250	500		mV_{DC}
Output Leakage Current	$V_{IN(+)} = 1 V_{DC}, V_{IN(-)} = 0,$ $V_O = 5 V_{DC}$	0.1			0.1			0.1			nA_{DC}

Electrical Characteristics $(V^+ = 5.0 V_{DC}, \text{ (Note 4)})$

Parameter	Conditions	LM139A			LM239A, LM339A			LM139			Units
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage	(Note 9)	4.0			4.0			9.0			mV_{DC}
Input Offset Current	$I_{IN(+)} - I_{IN(-)}, V_{CM} = 0V$	100			150			100			nA_{DC}
Input Bias Current	$I_{IN(+)}$ or $I_{IN(-)}$ with Output in Linear Range, $V_{CM} = 0V$ (Note 5)	300			400			300			nA_{DC}
Input Common-Mode Voltage Range	$V^+ = 30 V_{DC}$ (LM3302, $V^+ = 28 V_{DC}$) (Note 6)	0	$V^+ - 2.0$		0	$V^+ - 2.0$		0	$V^+ - 2.0$		V_{DC}

Electrical Characteristics (Continued) $(V^+ = 5.0 V_{DC}, \text{ (Note 4)})$

Parameter	Conditions	LM139A		LM239A, LM339A			LM139		Units	
		Min	Typ	Max	Min	Typ	Max	Min		Typ
Saturation Voltage	$V_{IN(-)} = 1 V_{DC}, V_{IN(+)} = 0,$ $I_{SINK} \leq 4 \text{ mA}$			700			700			mV_{DC}
Output Leakage Current	$V_{IN(+)} = 1 V_{DC}, V_{IN(-)} = 0,$ $V_O = 30 V_{DC}, \text{ (LM3302, } V_O = 28 V_{DC})$			1.0			1.0			μA_{DC}
Differential Input Voltage	Keep all V_{IN} 's $\geq 0 V_{DC}$ (or V^- , if used), (Note 8)			36			36			V_{DC}

Electrical Characteristics $(V^+ = 5.0 V_{DC}, \text{ (Note 4)})$

Parameter	Conditions	LM239, LM339			LM2901		LM3302		Units	
		Min	Typ	Max	Min	Typ	Max	Min		Typ
Input Offset Voltage	(Note 9)			9.0	9	15		40		mV_{DC}
Input Offset Current	$I_{IN(+)} - I_{IN(-)}, V_{CM} = 0V$			150	50	200		300		nA_{DC}
Input Bias Current	$I_{IN(+)}$ or $I_{IN(-)}$ with Output in Linear Range, $V_{CM} = 0V$ (Note 5)			400	200	500		1000		nA_{DC}
Input Common-Mode Voltage Range	$V^+ = 30 V_{DC}$ (LM3302, $V^+ = 28 V_{DC}$) (Note 6)			$V^+ - 2.0$	0	$V^+ - 2.0$	0	$V^+ - 2.0$		V_{DC}
Saturation Voltage	$V_{IN(-)} = 1 V_{DC}, V_{IN(+)} = 0,$ $I_{SINK} \leq 4 \text{ mA}$			700	400	700		700		mV_{DC}
Output Leakage Current	$V_{IN(+)} = 1 V_{DC}, V_{IN(-)} = 0,$ $V_O = 30 V_{DC}, \text{ (LM3302, } V_O = 28 V_{DC})$			1.0		1.0		1.0		μA_{DC}
Differential Input Voltage	Keep all V_{IN} 's $\geq 0 V_{DC}$ (or V^- , if used), (Note 8)			36		36		28		V_{DC}

Note 1: For operating at high temperatures, the LM339/LM339A, LM2901, LM3302 must be derated based on a 125°C maximum junction temperature and a thermal resistance of 95°C/W which applies for the device soldered in a printed circuit board, operating in a still air ambient. The LM239 and LM139 must be derated based on a 150°C maximum junction temperature. The low bias dissipation and the "ON-OFF" characteristic of the outputs keeps the chip dissipation very small ($P_D \leq 100 \text{ mW}$), provided the output transistors are allowed to saturate.

Note 2: Short circuits from the output to V^+ can cause excessive heating and eventual destruction. When considering short circuits to ground, the maximum output current is approximately 20 mA independent of the magnitude of V^+ .

Note 3: This input current will only exist when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistors becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also lateral NPN parasitic transistor action on the IC chip. This transistor action can cause the output voltages of the comparators to go to the V^+ voltage level (or to ground for a large overdrive) for the time duration that an input is driven negative. This is not destructive and normal output states will re-establish when the input voltage, which was negative, again returns to a value greater than $-0.3 V_{DC}$ (at 25°C).

Note 4: These specifications are limited to $-55^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$, for the LM139/LM139A. With the LM239/LM239A, all temperature specifications are limited to $-25^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$, the LM339/LM339A temperature specifications are limited to $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$, and the LM2901, LM3302 temperature range is $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$.

Note 5: The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so no loading change exists on the reference or input lines.

Note 6: The input common-mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is $V^+ - 1.5V$ at 25°C, but either or both inputs can go to $+30 V_{DC}$ without damage (25V for LM3302), independent of the magnitude of V^+ .

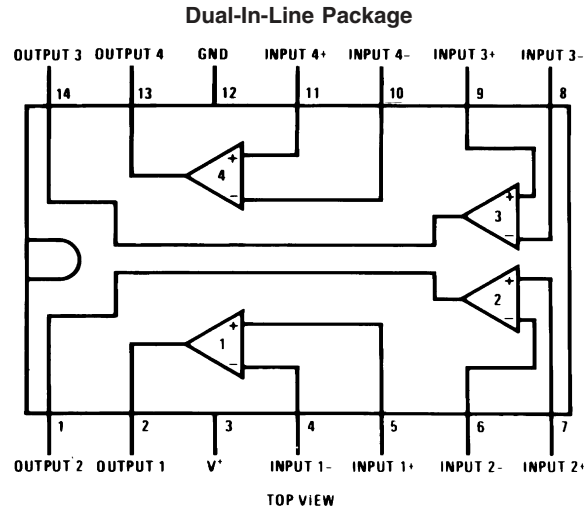
Note 7: The response time specified is a 100 mV input step with 5 mV overdrive. For larger overdrive signals 300 ns can be obtained, see typical performance characteristics section.

Note 8: Positive excursions of input voltage may exceed the power supply level. As long as the other voltage remains within the common-mode range, the comparator will provide a proper output state. The low input voltage state must not be less than $-0.3 V_{DC}$ (or $0.3 V_{DC}$ below the magnitude of the negative power supply, if used) (at 25°C).

Note 9: At output switch point, $V_O = 1.4 V_{DC}$, $R_S = 0\Omega$ with V^+ from $5 V_{DC}$ to $30 V_{DC}$; and over the full input common-mode range ($0 V_{DC}$ to $V^+ - 1.5 V_{DC}$), at 25°C. For LM3302, V^+ from $5 V_{DC}$ to $28 V_{DC}$.

Note 10: Refer to RETS139AX for LM139A military specifications and to RETS139X for LM139 military specifications.

Connection Diagrams



00570602

Order Number LM139J, LM139J/883 (Note 11), LM139AJ,
LM139AJ/883 (Note 12), LM239J, LM239AJ, LM339J

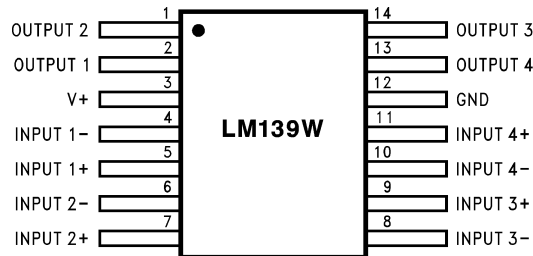
See NS Package Number J14A

Order Number LM339AM, LM339AMX, LM339M, LM339MX or LM2901M

See NS Package Number M14A

Order Number LM339N, LM339AN, LM2901N or LM3302N

See NS Package Number N14A



00570627

Order Number LM139AW/883 or LM139W/883 (Note 11)

See NS Package Number W14B,

LM139AWGRQMLV (Note 13)

See NS Package Number WG14A

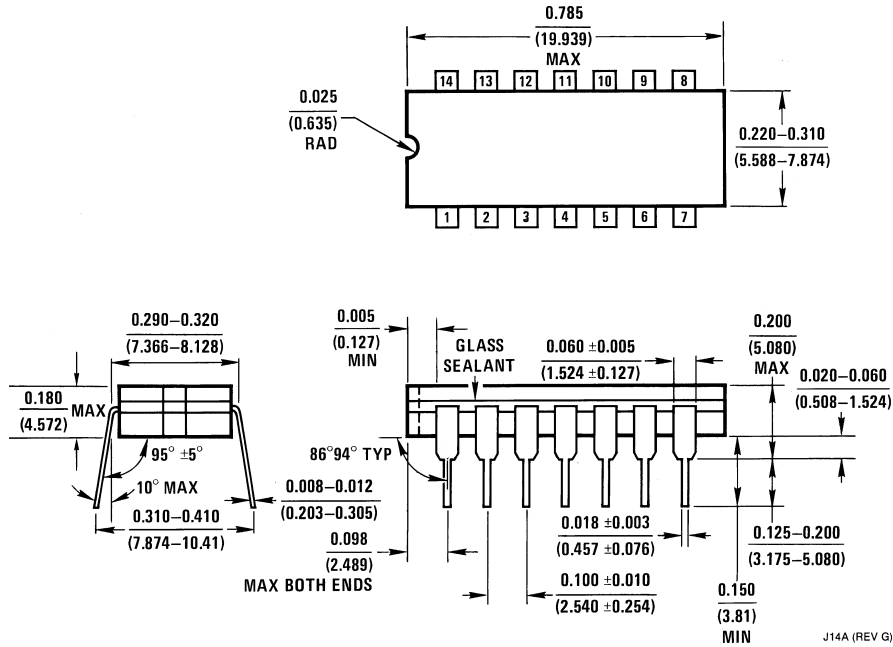
Note 11: Available per JM38510/11201

Note 12: Available per SMD# 5962-8873901

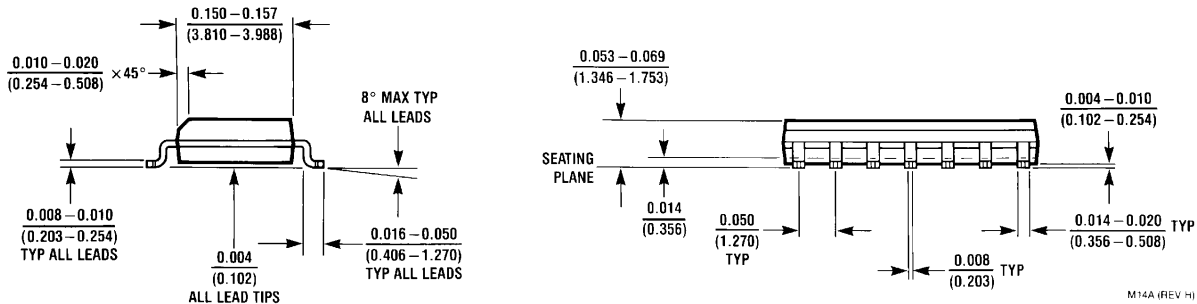
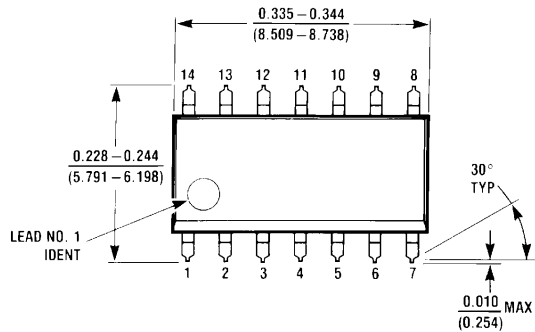
Note 13: See STD Mil Dwg 5962R96738 for Radiation Tolerant Device

Physical Dimensions inches (millimeters)

unless otherwise noted



Ceramic Dual-In-Line Package (J)
Order Number LM139J, LM139J/883, LM139AJ,
LM139AJ/883, LM239J, LM239AJ, LM339J
NS Package Number J14A



S.O. Package (M)
Order Number LM339AM, LM339AMX, LM339M, LM339MX, LM2901M or LM2901MX
NS Package Number M14A